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# **Development of High Efficiency Integrated Micro**transformers on Silicon for Power & **Signal Isolation**

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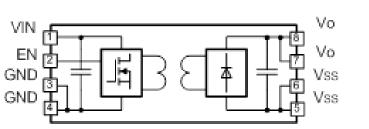
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## **Background & Motivation**

Footprint (mm <sup>2</sup> )	Volume (mm <sup>3</sup> )	Frequency MHz	
50	150	1	
30	25	5	
7.0	3.5	20	
2.0	1.0	50-100	



#### **Isolated Integrated bias supply**





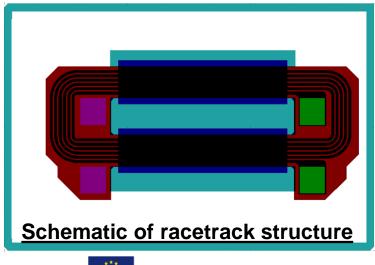
Isolated Converter Specs				
Switching Frequency	20 MHz			
Turns ratio	1:1			
Footprint	<4 mm <sup>2</sup>			
Input Voltage	5V			
Output Voltage	5V			
Load Current	100 mA			



### µ-transformers on Silicon technology-Design & Optimization

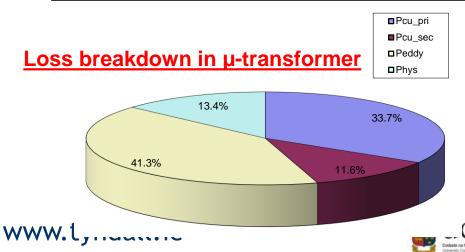
#### In-house optimization tool

- Racetrack structure
  - higher magnetizing inductance
  - good coupling factor
  - anisotropic core
- Ni<sub>45</sub>Fe<sub>55</sub> as core material





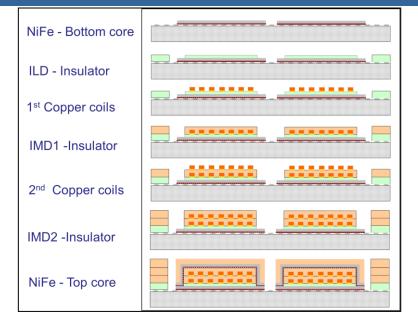
Transformer Prototype	Design 1	Design 2
Winding width, $\mu m$	40	45
Winding thickness, µm	15	15
Winding spacing, µm	15	15
Turns ratio,	6:6	7:7
Core thickness, $\mu m$	4.1	4.1
Core length, mm	1.32	1.58
Device length, mm	2.59	3
Device width, mm	1.15	1.35
DC resistance, Ohm	1.1	1.33
Inductance at 20MHz, nH	210	280

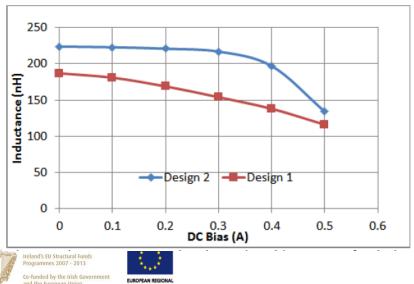


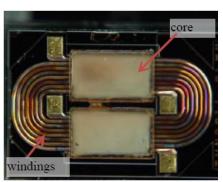


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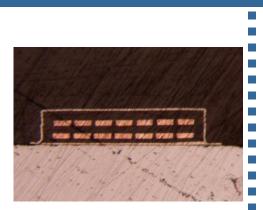
### µ-transformers on Silicon technology-**Fabrication & Characterization**



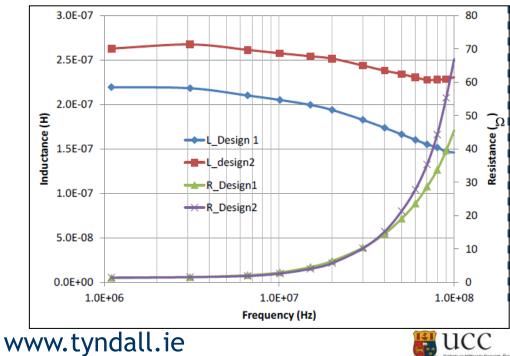




Top View



Cross-section





#### µ-transformers on Silicon technology-Converter tests & Conclusion

TP1 G	PRI P2 O PRI P1 PRI 52 O PRI 0 PRI 51 SEC 52 O PRI 0 SEC 51	Converter test results		
TP2 O		Technology	Air-core	This Work
TP4 TP6 0 TP8	TEXAS INSTRUMENTS INSTRUMENTS STRUCTURE TEST EVW REF#	Footprint	2mm <sup>2</sup>	3mm <sup>2</sup>
Pier I Litt Verdicel Restance Trig Deglerr Custors Measure Meak Web VerScope Analyze Usbalen Heb T		Inductance	8 nH	270 nH
Sec Sec	econdary voltage — DC voltage at output filter	Inductance density	17nH/mm <sup>2</sup>	80nH/mm <sup>2</sup>
	nary voltage	Frequency	180 MHz	20 MHz
Primary current	nary current	Coupling	0.85	0.97
		Efficiency	70%	78.2%
Image: Proper till Image: till   Image: Till				

- ✓ Batch micro-fabricated transformers with advanced double layer metal process
- ✓ High Voltage Gain >-1dB at 10~40MHz
- $\checkmark$  High measured efficiency of 78% at 20MHz
- $\checkmark$  Higher converter efficiency @ 20MHz (> 60%) than air-core based solutions
- ✓ Small footprint area (<3mm<sup>2</sup>); Power density- 110 W/cm<sup>3</sup>
- \*The authors acknowledge Enterprise Ireland for Funding this work.